

VHF-to-Microwave, +3V, General-Purpose Amplifiers

General Description

The MAX2630/MAX2631/MAX2632/MAX2633 are low-voltage, low-noise amplifiers for use from VHF to microwave frequencies. Operating from a single +2.7V to +5.5V supply, these devices have a flat gain response to 900MHz. Their low noise figure and low supply current make them ideal for receive, buffer, and transmit IF applications.

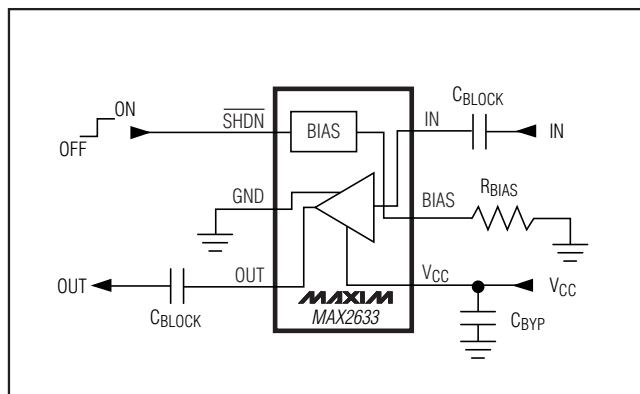
The MAX2630/MAX2631 are biased internally, eliminating the need for external bias resistors or inductors. The MAX2632/MAX2633 have a user-selectable supply current, which can be adjusted by adding a single external resistor. This allows customized output power and gain according to specific applications requirements. The MAX2631/MAX2633 feature a shutdown pin that allows them to be powered down to less than 1µA supply current. Aside from a single bias resistor required for the MAX2632/MAX2633, the only external components needed for this family of amplifiers are input and output blocking capacitors and a V_{CC} bypass capacitor.

The MAX2630 comes in a 4-pin SOT143 package, requiring minimal board space. The MAX2631/MAX2632 come in small 5-pin SOT23 packages. The MAX2633 comes in a 6-pin SOT23 package.

Applications

Personal Communicating Systems	Cordless Phones
Global Positioning Systems	Cellular Phones
Wireless Local Area Networks	ISM Radios
Wireless Local Loops	TV Tuners
Land Mobile Radios	Set-Top Boxes

Typical Operating Circuit



Features

- ◆ Single +2.7V to +5.5V Operation
- ◆ Internally Biased (MAX2630/MAX2631)
- ◆ Adjustable Bias (MAX2632/MAX2633)
- ◆ 6.6mA Supply Current (insensitive to supply voltage)
- ◆ 1µA Shutdown Current (MAX2631/MAX2633)
- ◆ 3.7dB Noise Figure
- ◆ 13.4dB Gain
- ◆ Ultra-Small SOT Packages

Ordering Information

PART	TEMP RANGE
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ABSOLUTE MAXIMUM RATINGS

V_{CC} to GND-0.3V to 6V
 Input Power5dBm
 OUT Current±12mA
 IN to GND Voltage-1.2V to 1.2V
 Bias to GND Voltage0.0V to 3V
 Voltage at SHDN Input
 (MAX2631/MAX2633)-0.3V to (V_{CC} + 0.3V)
 Current into SHDN Input (MAX2631/MAX2633)100μA

Continuous Power Dissipation (T_A = +70°C)
 SOT143 (derate 4mW/°C above +70°C)320mW
 SOT23-5 (derate 7.1mW/°C above +70°C)571mW
 SOT23-6 (derate 7.1mW/°C above +70°C)571mW
 Operating Temperature Range-40°C to +85°C
 Junction Temperature+150°C
 Storage Temperature Range-65°C to +150°C
 Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



CAUTION! ESD SENSITIVE DEVICE

ELECTRICAL CHARACTERISTICS

(V_{CC} = +3V, Z₀ = 50Ω, f_{IN} = 900MHz, R_{BIAS} = 10kΩ (MAX2632/MAX2633), V_{SHDN} = V_{CC} (MAX2631/MAX2633), T_A = +25°C, unless otherwise noted.)

PARAMETERS	CONDITIONS	MIN	TYP	MAX	UNITS
Operating Temperature Range	(Note 1)	-40		85	degrees
Supply Voltage		2.7		5.5	V
Power Gain	T _A = +25°C	11	13.4	16.5	dB
	T _A = T _{MIN} to T _{MAX} (Note 1)	9.4		18.4	
Noise Figure			3.8		dB

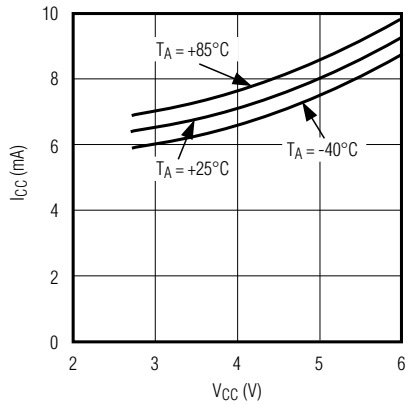
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Typical Operating Characteristics

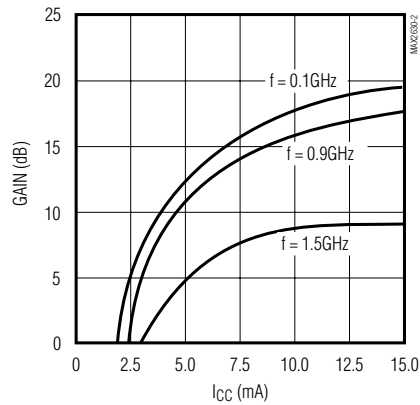
($V_{CC} = +3V$, $V_{SHDN} = V_{CC}$ (MAX2631/MAX2633), $Z_0 = 50\Omega$, $f_{IN} = 900MHz$, $R_{BIAS} = 10k\Omega$ (MAX2632/MAX2633), $T_A = +25^\circ C$, unless otherwise noted.)

MAX2630-MAX2633

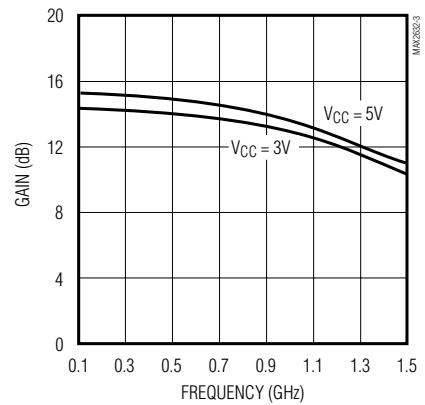
SUPPLY CURRENT vs. SUPPLY VOLTAGE



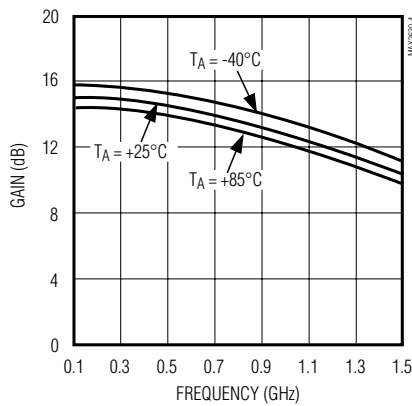
**MAX2632/MAX2633
GAIN vs. SUPPLY CURRENT**



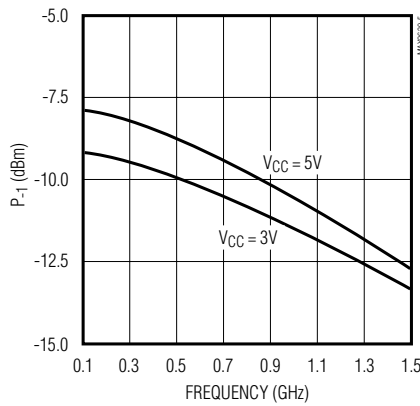
GAIN vs. FREQUENCY AND VOLTAGE



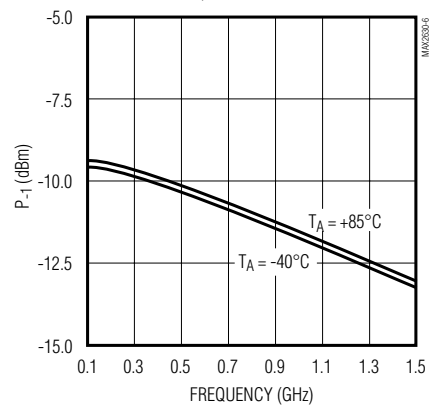
**GAIN vs. FREQUENCY
AND TEMPERATURE**



**OUTPUT 1dB COMPRESSION
POWER vs. FREQUENCY AND VOLTAGE**



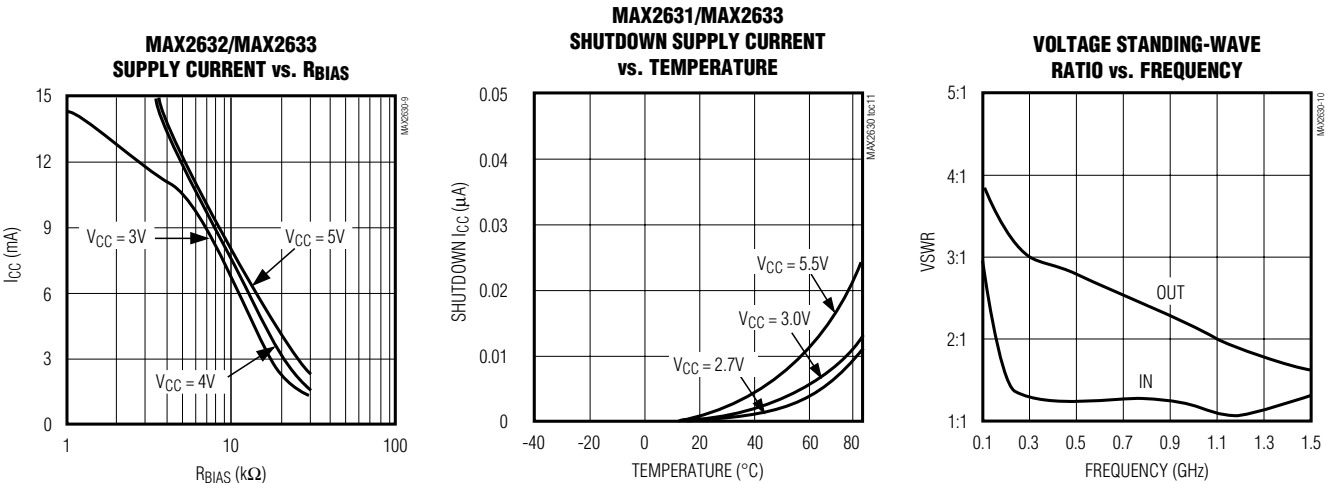
**OUTPUT 1dB COMPRESSION
POWER vs. FREQUENCY AND TEMPERATURE**



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Typical Operating Characteristics (continued)

($V_{CC} = +3V$, $V_{\overline{SHDN}} = V_{CC}$ (MAX2631/MAX2633), $Z_0 = 50\Omega$, $f_{IN} = 900MHz$, $R_{BIAS} = 10k\Omega$ (MAX2632/MAX2633), $T_A = +25^\circ C$, unless otherwise noted.)



Pin Description

PIN				NAME	FUNCTION
MAX2630	MAX2631	MAX2632	MAX2633		
3	5	5	6	IN	Amplifier Input. Use a series blocking capacitor with less than 3 Ω reactance at your lowest operating frequency.
2	2	2	2	GND	

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MAX2630-MAX2633

Table 1a. Typical Scattering Parameters

($V_{CC} = +3V$, $V_{SHDN} = V_{CC}$, $Z_0 = 50\Omega$, $R_{BIAS} = 10k\Omega$, $T_A = +25^\circ C$.)

FREQUENCY (GHz)	S11 (mag)	S11 (ang)	S21 (dB)	S21 (mag)	S21 (ang)	S12 (dB)	S12 (mag)	S12 (ang)	S22 (mag)	S22 (ang)	K
0.05	0.59	-50	12.9	4.39	46	-38.7	0.012	37	0.62	-19	4.30
0.10	0.37	-70	14.2	5.11	1	-36.7	0.015	12	0.57	-29	4.07
0.20	0.22	-86	14.5	5.32	-49	-35.8	0.016	-13	0.54	-49	3.93
0.30	0.17	-100	14.5	5.32	-89	-35.0	0.018	-32	0.53	-71	3.74
0.40	0.16	-109	14.5	5.28	-125	-34.4	0.019	-51	0.51	-94	3.61
0.50	0.15	-99	14.3	5.19	-138	-33.6	0.021	-70	0.50	-118	3.45
0.60	0.14	-86	14.1	5.05	-127	-33.0	0.022	-89	0.48	-109	3.38
0.70	0.14	-68	13.9	4.93	-116	-32.2	0.025	-107	0.46	-96	3.27
0.80	0.14	-49	13.5	4.75	-104	-31.3	0.027	-124	0.44	-82	3.16
0.90	0.13	-									

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Table 1b. MAX2633 Typical Scattering Parameters

($V_{CC} = +5V$, $V_{SHDN} = V_{CC}$, $Z_0 = 50\Omega$, $R_{BIAS} = 10k$, $T_A = +25^\circ C$.)

FREQUENCY (GHz)	S11 (mag)	S11 (ang)	S21 (dB)	S21 (mag)	S21 (ang)	S12 (dB)	S12 (mag)	S12 (ang)	S22 (mag)	S22 (ang)	K
0.05	0.58	-53	13.6	4.80	45	-39.2	0.011	36	0.62	-22	4.26
0.10	0.35	-76	15.0	5.62	1	-36.9	0.014	13	0.57	-29	3.83
0.20	0.20	-97	15.4	5.87	-48	-36.1	0.016	-14	0.55	-49	3.75
0.30	0.14	-101	15.4	5.91	-87	-35.2	0.017	-31	0.53	-72	3.48
0.40	0.12	-94	15.4	5.91	-123	-34.7	0.018	-50	0.52	-95	3.35
0.50	0.11	-82	15.4	5.87	-141	-33.8	0.020	-68	0.51	-119	3.14
0.60	0.11	-66	15.2	5.78	-130	-33.1	0.022	-86	0.49	-108	3.02
0.70	0.11	-45	15.1	5.68	-119	-32.3	0.024	-104	0.48	-94	2.87
0.80	0.11	-22	14.9	5.54	-108	-31.3	0.027	-121	0		

VHF-to-Microwave, +3V, General-Purpose Amplifiers

MAX2630-MAX2633

Detailed Description

The MAX2630-MAX2633 are broadband amplifiers with 3dB bandwidth greater than 1GHz. Their small size and internal bias circuitry make them ideal for applications where board space is limited. The MAX2632/MAX2633 have a user-selectable bias current that allows the user to set both gain and output power for a particular application, and the MAX2631/MAX2633 incorporate shut-down capability.

Applications Information

External Components

The MAX2630-MAX2633 are easy to use, as shown in the *Typical Operating Circuit* and Figures 1, 2 and 3. Input and output series capacitors may be necessary to block DC bias voltages generated by the amplifiers from interacting with adjacent circuitry. These capacitors must be large enough to contribute negligible reactance in a 50Ω system at the minimum operating frequency. Use the following equation to calculate their minimum value:

$$C_{\text{BLOCK}} = \frac{53,000}{f} \text{ (pF)}$$

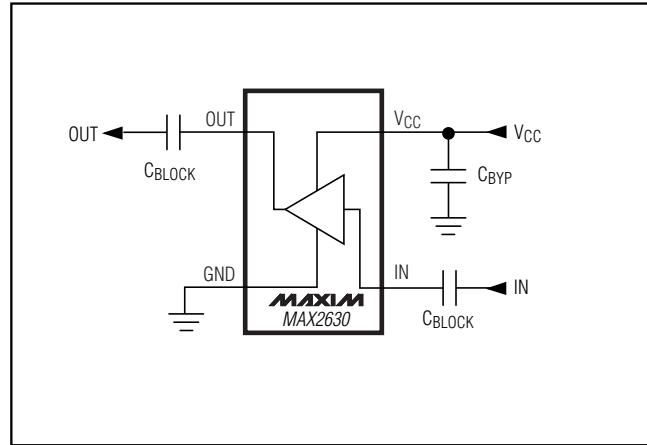
where f (in megahertz) is the minimum operating frequency.

The V_{CC} pin must be RF bypassed for correct operation. To accomplish this, connect a capacitor between the V_{CC} pin and ground, as close to the package as is practical. Use the same equation given above (for DC-blocking capacitor values) to calculate the minimum capacitor value. If the PC board has long V_{CC} lines, additional bypassing may be necessary. This can be done farther away from the package, if needed.

Proper grounding of the GND pin is essential. If the PC board uses a topside RF ground, connect it directly to the GND pin. For a board where the ground plane is not on the component side, the best technique is to connect the GND pin to it with a plated through-hole close to the package.

An on-chip buffer at the MAX2631/MAX2633's SHDN pin makes bypassing this pin unnecessary except in very noisy applications. When RF filtering is needed, use a bypass capacitor similar to the one used on V_{CC} . Since negligible current flows into this pin, additional RF filtering may be done with a series resistor.

To set the MAX2632/MAX2633's supply current, connect a resistor from the BIAS pin to ground. To estimate the value of this resistor, refer to the graph Supply Current vs. R_{BIAS} in the *Typical Operating Characteristics*.



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PC Board Layout Example

Example PC board layouts are given in Figures 4 to 7. They use FR-4 with a 31mil layer thickness between the RF lines and the ground plane. The boards satisfy all of the above recommendations.

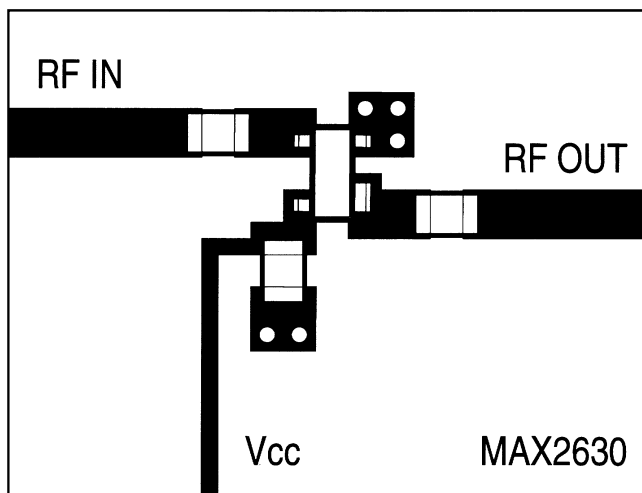


Figure 4. MAX2630 Example PC Board Layout

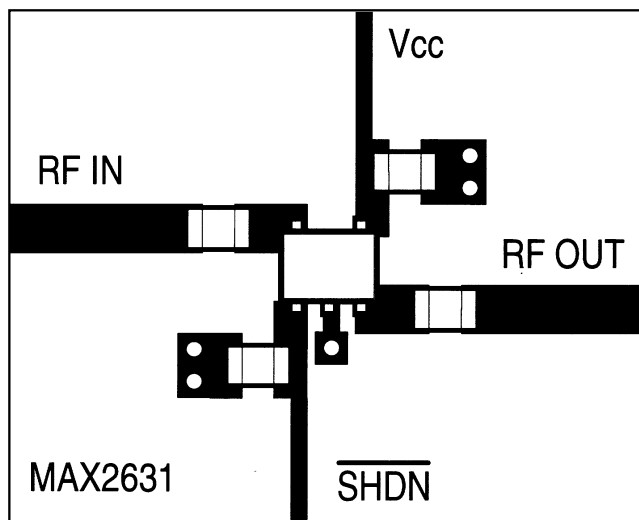


Figure 5. MAX2631 Example PC Board Layout

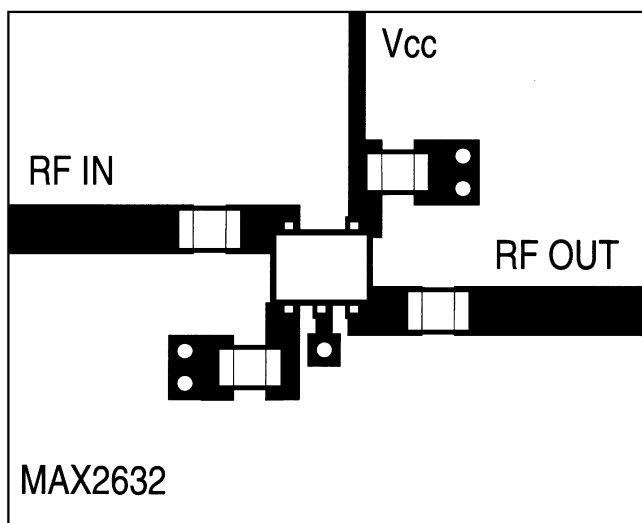


Figure 6. MAX2632 Example PC Board Layout

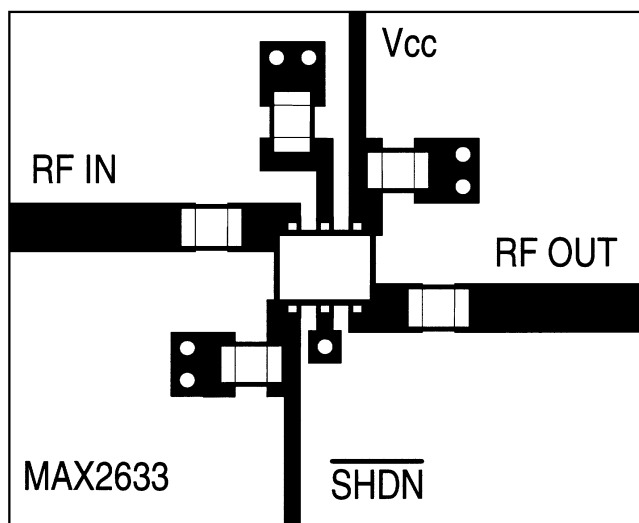


Figure 7. MAX2633 Example PC Board Layout

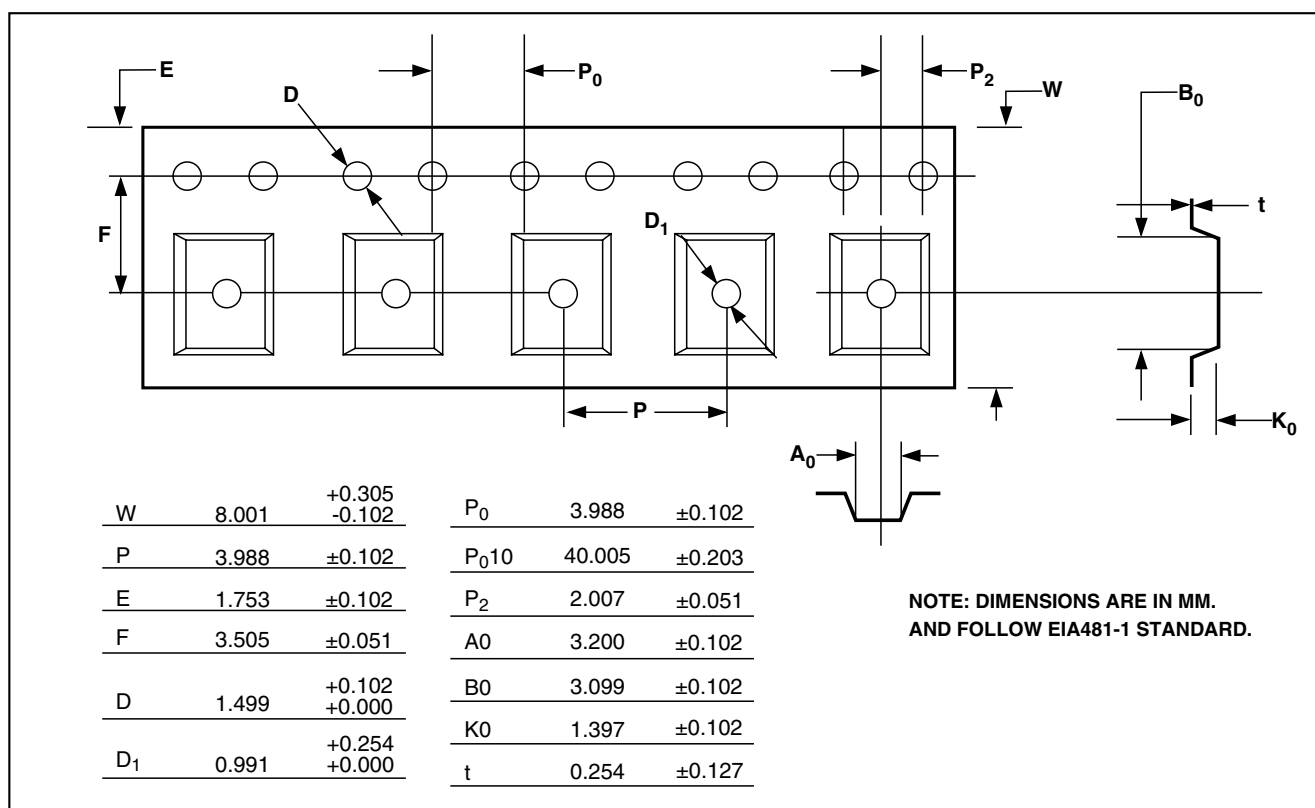
VHF-to-Microwave, +3V, General-Purpose Amplifiers

MAX2630-MAX2633

Chip Information

TRANSISTOR COUNT: 199

Tape-and-Reel Information



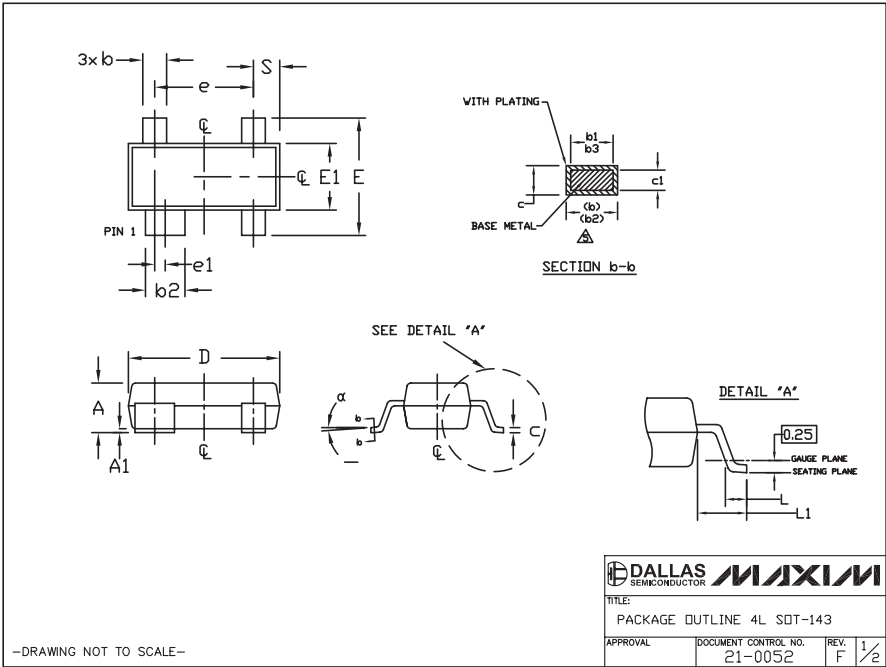
Revision History

Pages changed at Rev 3: 1, 4, 9-12.

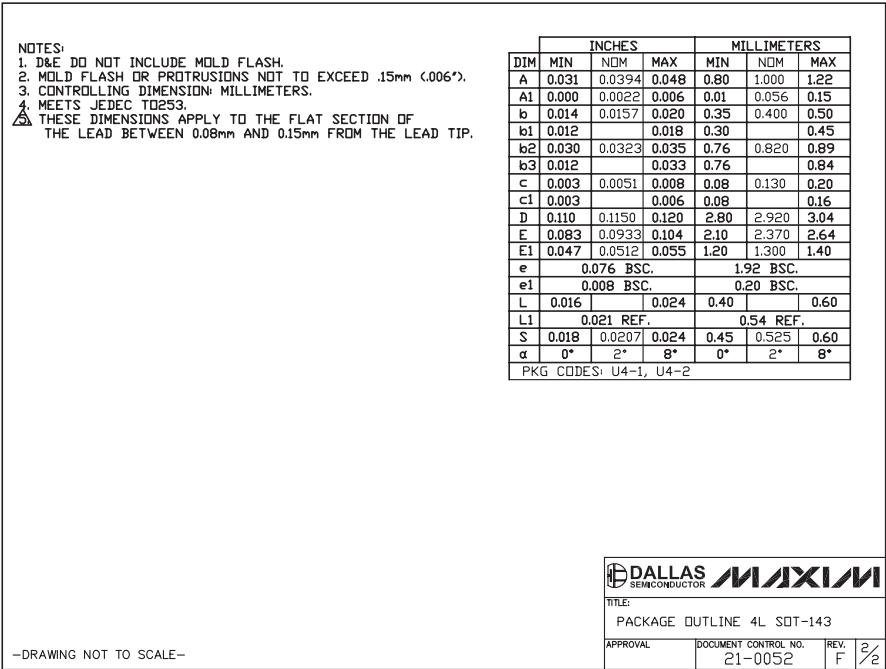
VHF-to-Microwave, +3V, General-Purpose Amplifiers

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



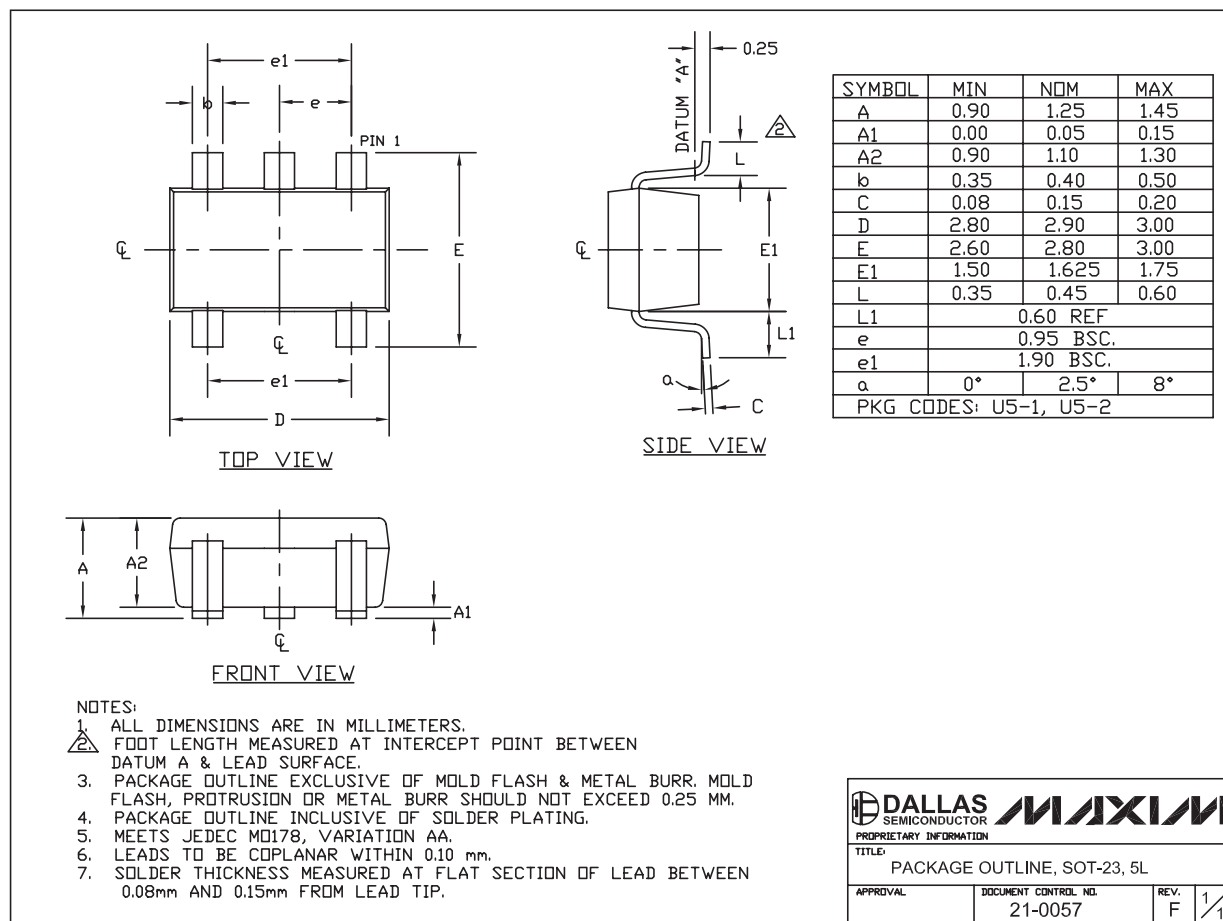
SOT-23 5L EPS



VHF-to-Microwave, +3V, General-Purpose Amplifiers

Package Information (continued)

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VHF-to-Microwave, +3V, General-Purpose Amplifiers

Package Information (continued)

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